

CMOS Digital Integrated Circuits Silicon Monolithic

TC7WBL3305CFK,TC7WBL3306CFK

1. Functional Description

· Low-Voltage, Low-Capacitance Dual Bus Switch

2. General

The TC7WBL3305CFK and TC7WBL3306CFK are Low Voltage/Low Capacitance CMOS 2bit Bus Switches. The low ON-resistance of the switch allows connections to be made with minimal propagation delay time.

The TC7WBL33306CFK requires the output enable (\overline{OE}) input to be set high to place the output into the high impedance state, whereas the TC7WBL3305CFK requires the output enable (OE) input to be set low to place the output into the high impedance.

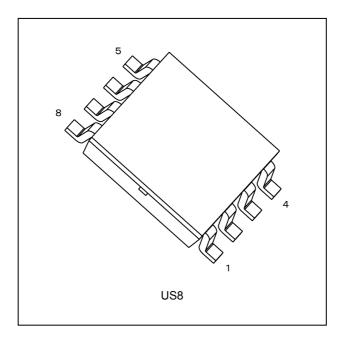
All inputs are equipped with protection circuits against static discharge.

3. Features

- (1) Wide operating temperature range: $T_{opr} = -40$ to 125 °C (Note 1)
- (2) Operating voltage: $V_{CC} = 1.65$ to 3.6 V
- (3) ON capacitance: $C_{I/O} = 7$ pF Switch On (typ.) $@V_{CC} = 3.0$ V
- (4) ON resistance: $R_{ON} = 6.0 \Omega$ (typ.) @ $V_{CC} = 3.0 \text{ V}$, $V_{IS} = 0 \text{ V}$
- (5) Power-down protection for inputs (OE and \overline{OE} , I/O)
- (6) Package: US8

Note 1: For devices with the ordering part number ending in (CT. Topr = -40 to 85 °C for the other devices.

4. Packaging

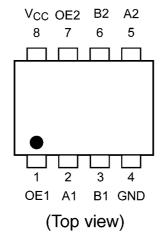


Start of commercial production

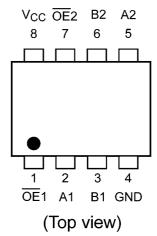


5. Pin Assignment



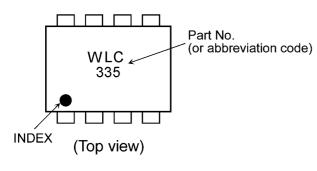


TC7WBL3306CFK

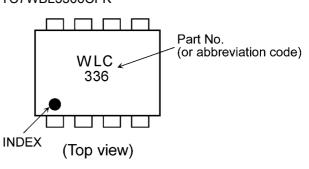


6. Marking



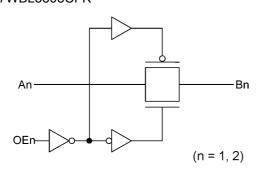


TC7WBL3306CFK

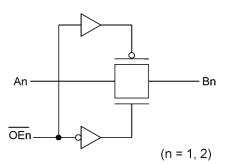


7. Block Diagram

TC7WBL3305CFK



TC7WBL3306CFK



8. Truth Table

Inputs OE (TC7WBL3305CFK)	Inputs OE (TC7WBL3306CFK)	Function
Н	L	A port = B port
L	Н	Disconnect



9. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 4.6	V
Input voltage (OE, OE)	V _{IN}		-0.5 to 4.6	V
Switch I/O voltage	Vs	V _{CC} = 0 V or Switch = Off	-0.5 to 4.6	V
		Switch = On	-0.5 to V _{CC} +0.5	
Clamp diode current	I _{IK}		-50	mA
Switch I/O current	I _S		50	mA
Power dissipation	P _D		200	mW
V _{CC} /ground current	I _{CC} /I _{GND}		±100	mA
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

10. Operating Ranges (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V _{CC}			1.65 to 3.6	V
Input voltage (OE, OE)	V_{IN}			0 to 3.6	V
Switch I/O voltage	Vs		V _{CC} = 0 V or Switch = Off	0 to 3.6	V
			Switch = On	0 to V _{CC}	
Operating temperature	T _{opr}	(Note 1)		-40 to 125	°C
		(Note 2)		-40 to 85	
Input rise time	dt/dv			0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused control inputs must be tied to either V_{CC} or GND.

Note 1: For devices with the ordering part number ending in (CT.

Note 2: For devices except those with the ordering part number ending in (CT.

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11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage (OE, OE)	V _{IH}		_	1.65 to 3.6	0.7 × V _{CC}	_	_	V
Low-level input voltage (OE, OE)	V _{IL}		_	1.65 to 3.6		_	$0.3 \times V_{CC}$	V
Input leakage current (OE, OE)	I _{IN}		V _{IN} = 0 to 3.6 V	1.65 to 3.6		_	±1.0	μА
Power-OFF leakage current	l _{OFF}		OE, OE , A, B = 0 to 3.6 V	0	_	_	10	μА
Switch OFF-state leakage current	I _{SZ}		A, B = 0 V to V_{CC} , OE = GND (TC7WBL3305CFK), OE = V_{CC} (TC7WBL3306CFK)	1.65 to 3.6		_	±1.0	μА
ON-resistance	R _{ON}	(Note 1), (Note 2)	$V_{IS} = 0 \text{ V},$ $I_{IS} = 30 \text{ mA}$	3.0		6.0	10.5	Ω
			$V_{IS} = 3.0 \text{ V},$ $I_{IS} = 30 \text{ mA}$	3.0		11	17	
			V _{IS} = 2.4 V, I _{IS} = 15 mA	3.0	_	12	19	
			V _{IS} = 0 V, I _{IS} = 24 mA	2.3	_	6.5	12	
			V _{IS} = 2.3 V, I _{IS} = 24 mA	2.3	_	13	21	
			V _{IS} = 2.0 V, I _{IS} = 15 mA	2.3	_	15	22	
			V _{IS} = 0 V, I _{IS} = 4 mA	1.65	_	8	14	
			V _{IS} = 1.65 V, I _{IS} = 4 mA	1.65	_	18	27	
Quiescent supply current	I _{CC}		$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$ A	3.6	_	_	10	μА

Note 1: All typical values are at T_a = 25 °C.

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Note 2: Measured by the voltage drop between A and B pins at the indicated current through the switch. On-resistance is determined by the lower of the voltages on the two (A or B) pins.



11.1.1. DC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}		_	1.65 to 3.6	0.7 × V _{CC}	_	V
Low-level input voltage	V _{IL}		_	1.65 to 3.6	_	$0.3 \times V_{CC}$	
Input leakage current	I _{IN}		V _{IN} = 0 to 3.6 V	1.65 to 3.6	_	±10.0	μА
Power-OFF leakage current	I _{OFF}		OE, OE , A, B = 0 to 3.6 V	0	_	40	μΑ
Switch OFF-state leakage current	I _{SZ}		A, B = 0 V to V_{CC} , OE = GND(TC7WBL3305CFK), OE = V_{CC} (TC7WBL3306CFK)	1.65 to 3.6	_	±10.0	μА
ON-resistance	R _{ON}	(Note 1), (Note 2)	· · ·	3.0	_	13	Ω
			$V_{IS} = 3.0 \text{ V},$ $I_{IS} = 30 \text{ mA}$	3.0	_	20	
			V _{IS} = 2.4 V, I _{IS} = 15 mA	3.0	_	22	
			V _{IS} = 0 V, I _{IS} = 24 mA	2.3	_	15	
			V _{IS} = 2.3 V, I _{IS} = 24 mA	2.3	_	24	
			V _{IS} = 2.0 V, I _{IS} = 15 mA	2.3	_	25	
			V _{IS} = 0 V, I _{IS} = 4 mA	1.65	_	17	
			V _{IS} = 1.65 V, I _{IS} = 4	1.65	_	30	
Quiescent supply current	I _{CC}		V _{IN} = V _{CC} or GND, I _{OUT} = 0 A	3.6	_	40	μА

Note 1: All typical values are at T_a = 25 °C.

Note 2: Measured by the voltage drop between A and B pins at the indicated current through the switch. On-resistance is determined by the lower of the voltages on the two (A or B) pins.

11.2. AC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Output enable time	t_{PZL}, t_{PZH}	See Fig. 11.2.1, 11.2.2,	3.3 ± 0.3	_	6	ns
		Table 11.2.1	2.5 ± 0.2	_	7	
			1.8 ± 0.15	_	10	
Output disable time	t_{PLZ}, t_{PHZ}	See Fig. 11.2.1, 11.2.2,	3.3 ± 0.3	_	6	ns
		Table 11.2.1	2.5 ± 0.2	_	7	
			1.8 ± 0.15	_	10	

11.2.1. AC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Output enable time	t_{PZL}, t_{PZH}	See Fig. 11.2.1, 11.2.2,	3.3 ± 0.3	_	8	ns
		Table 11.2.1	2.5 ± 0.2	_	9	
			1.8 ± 0.15	_	12	
Output disable time	t_{PLZ}, t_{PHZ}	See Fig. 11.2.1, 11.2.2,	3.3 ± 0.3	_	8	ns
		Table 11.2.1	2.5 ± 0.2	_	9	
			1.8 ± 0.15	_	12	

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11.3. Capacitive Characteristics (Note) (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	V _{IN} = 0 V	3.0	4	pF
Switch terminal OFF-capacitance	C _{I/O}		3.0	3.5	pF
Switch terminal ON-capacitance	C _{I/O}		3.0	7	pF

Note: Parameter guaranteed by design.

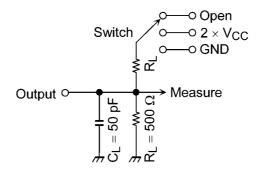


Fig. 11.2.1 AC Test Circuit

Table 11.2.1 Parameter for AC Test Circuit

Parameter	Switch
t_{PLZ} , t_{PZL}	$2\times V_{CC}$
t _{PHZ} , t _{PZH}	GND

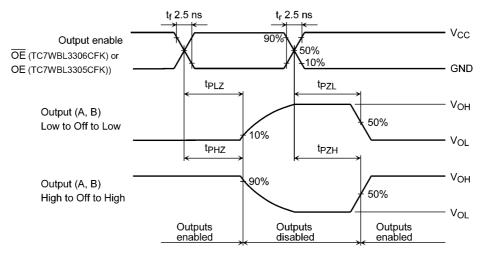


Fig. 11.2.2 AC Waveform t_{PLZ}, t_{PHZ}, t_{PZL}, t_{PZH}

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12. Rise and Fall Time (t_r/t_f)

The $t_{r(out)}$ and $t_{f(out)}$ values of the output signals are affected by the CR time constant of the input, which consists of the switch terminal capacitance $(C_{I\!/O})$ and the on-resistance (R_{ON}) of the input.

In practice, the $t_{r(out)}$ and $t_{f(out)}$ values are also affected by the circuit's capacitance and resistance components other than those of the TC7WBL3305CFK, TC7WBL3306CFK.

The t_{r(out)}/t_{r(out)} values can be approximated as follows. (Figure 12.1, Table 12.1 shows the test circuit.)

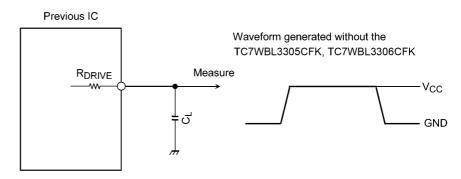
 $t_{r(out)}/t_{f(out)} \ (approx) = -\left(C_{L/O} + C_{L}\right) \ \cdot \ \left(R_{DRIVE} + R_{ON}\right) \ \cdot \ \ln \left(\left(\left(V_{OH} - V_{OL}\right) - V_{M}\right) / \left(V_{OH} - V_{OL}\right)\right)$ Where, R_{DRIVE} is the output impedance of the previous-stage circuit.

Calculation example:

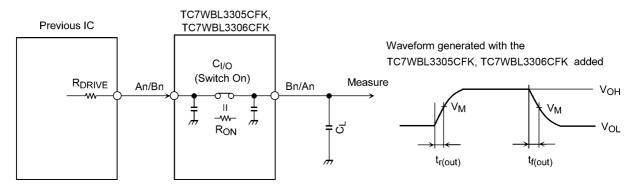
$$t_{r(out)}$$
 (approx) = - (7 + 15) E - 12 · (120 + 6) · ln (((3.0 - 0) - 1.5) / (3.0 - 0)) \approx 1.9 ns

Calculation conditions:

 $V_{CC} = 3.0 \text{ V}$, $C_L = 15 \text{ pF}$, $R_{DRIVE} = 120 \Omega$ (output impedance of the previous IC), $V_M = 1.5 \text{ V}$ ($V_{CC}/2$) Output of the previous IC = digital (i.e., high-level voltage = V_{CC}, low-level voltage = GND)



RDRIVE = output impedance of the previous IC



R_{DRIVE} = output impedance of the previous IC

Fig. 12.1 Calculation Circuit

Table 12.1 **Calculation Circuit**

Characteristics	V_{CC} = 3.3 \pm 0.3 V	V_{CC} = 2.5 ± 0.2 V	V _{CC} = 1.8 ± 0.15 V
V_{M}	V _{CC} /2	V _{CC} /2	V _{CC} /2

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13. Characteristics Curves (Note)

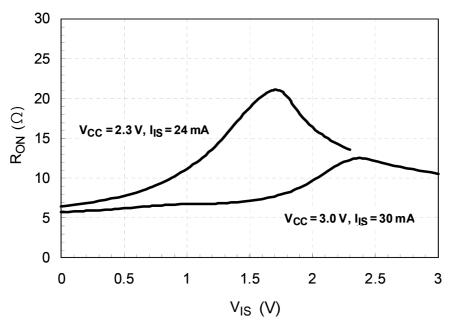


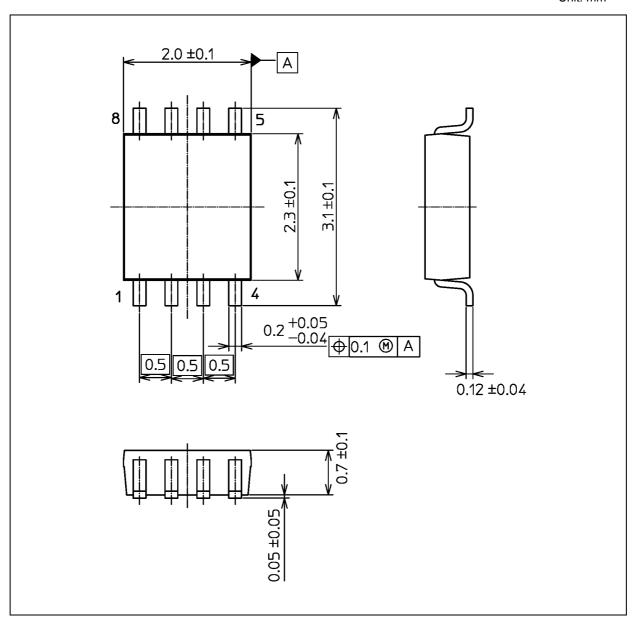
Fig. 13.1 R_{ON} - V_{IS} (typ.) ($T_a = 25$ °C)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 0.01 g (typ.)

	Package Name(s)
JEDEC: SOT-765	
Nickname: US8	

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